



DMT3009LFVW

30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	11mΩ @ V _{GS} = 10V	50A
30V	$13m\Omega @ V_{GS} = 4.5V$	45A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

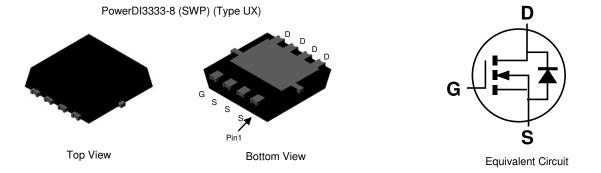
- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

Features and Benefits

- Low RDS(ON) Ensures On State Losses Are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher **Density End Products**
- Occupies Just 33% of The Board Area Occupied by SO-8 Enabling Smaller End Product
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMT3009LFVWQ)

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 📵
- Weight: 0.03 grams (Approximate)



Ordering Information (Note 4)

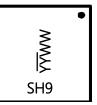
Part Number	Case	Packaging
DMT3009LFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000/Tape & Reel
DMT3009LFVW-13	PowerDI3333-8 (SWP) (Type UX)	3,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



SH9= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	30	V
Gate-Source Voltage	VGSS	±20	V	
	TA = +25°C TA = +70°C	ID	12 10	А
Continuous Drain Current V _{GS} = 10V	Tc = +25°C T _C = +70°C	lo	50 37	А
Maximum Continuous Body Diode Forward Current (Note 5)	•	ls	3	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		ldм	90	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 19	lsм	90	А	
Avalanche Current, L = 0.1mH		las	19	А
Avalanche Energy, L = 0.1mH		Eas	19	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

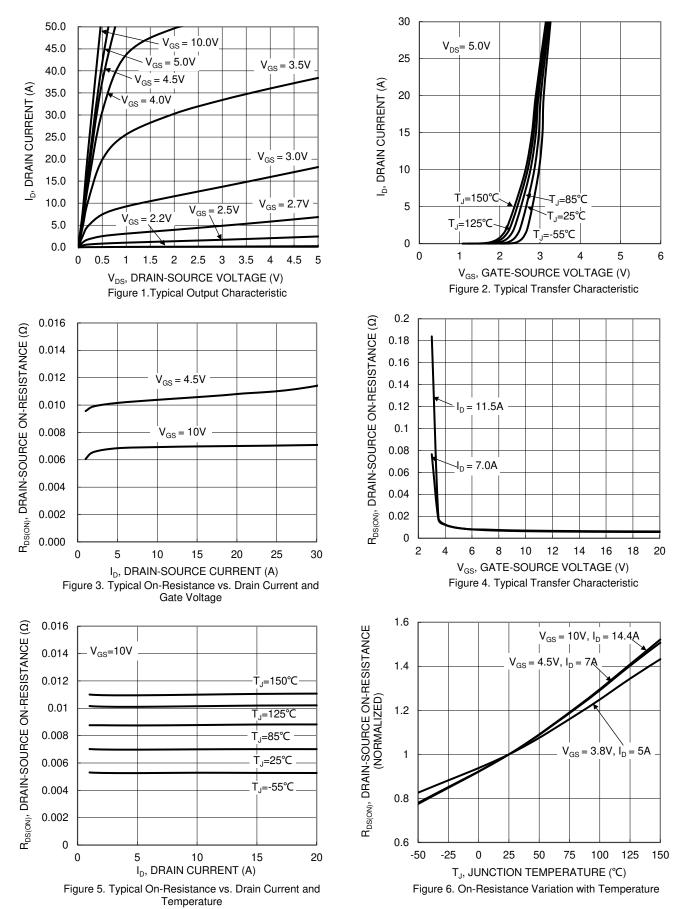
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	55	°C/W
Total Power Dissipation (Note 8)	Tc = +25°C	PD	35.7	W
Thermal Resistance, Junction to Case (Note 8)	Steady State	R _{0JC}	3.5	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

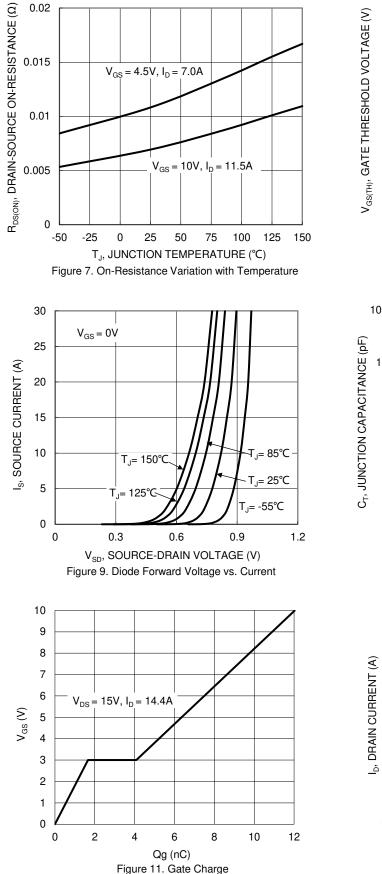
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)	- 		- 71-				
Drain-Source Breakdown Voltage	BVDSS	30	-	-	V	V _{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current	IDSS	-	-	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	-	-	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)						-	
Gate Threshold Voltage	VGS(TH)	1	-	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
		-	6.6	11	mΩ	VGS = 10V, ID = 14.4A	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	10.5	13		$V_{GS} = 4.5V, I_D = 7A$	
		-	13.4	20		VGS = 3.8V, ID = 5A	
Diode Forward Voltage	Vsd	-	0.8	1.2	V	VGS = 0V, IS = 10A	
DYNAMIC CHARACTERISTICS (Note 7)						·	
Input Capacitance	Ciss	-	823	-	pF	− V _{DS} = 15V, V _{GS} = 0V, − f = 1.0MHz	
Output Capacitance	Coss	-	352	-	pF		
Reverse Transfer Capacitance	Crss	-	52	-	pF		
Gate Resistance	Rg	-	1.2	-	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	5.8	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	-	12	-	nC		
Gate-Source Charge	Qgs	-	1.7	-	nC	V _{DS} = 15V, I _D = 14.4A	
Gate-Drain Charge	Qgd	-	2.4	-	nC	-	
Turn-On Delay Time	tD(ON)	-	3.2	-	ns		
Turn-On Rise Time	tR	-	5.2	-	ns	$V_{GS} = 10V, V_{DD} = 15V,$ $R_G = 1\Omega, I_D = 10A$	
Turn-Off Delay Time	tD(OFF)	-	8.9	-	ns		
Turn-Off Fall Time	tF	-	1.5	-	ns		
Body Diode Reverse Recovery Time	trr	-	16.4	-	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	-	5.9	-	nC	— IF = 10A, dI/dt = 100A/μs	

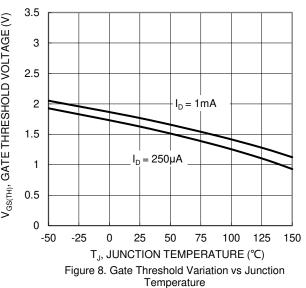
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.
Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

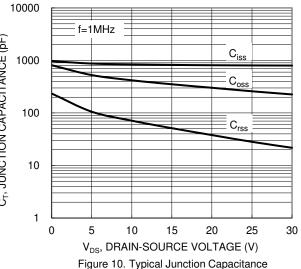


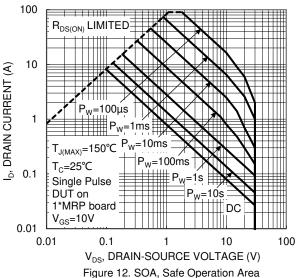




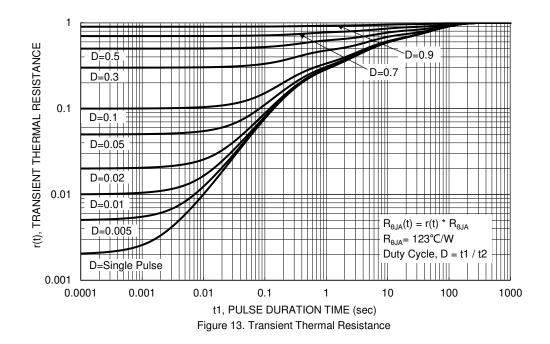








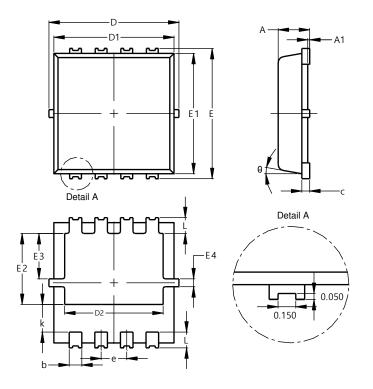






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



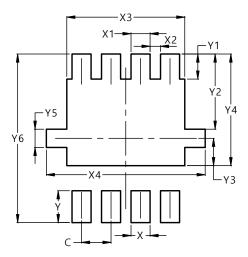
PowerDI3333-8 (SWP) (Type UX)

PowerDI3333-8 (SWP)						
(Type UX)						
Dim	Min	Min Max Ty				
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
E	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	-	-	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
X3	2.600			
X4	3.500			
Y	0.700			
Y1	0.550			
Y2	1.650			
Y3	0.600			
Y4	2.450			
Y5	0.400			
Y6	3.700			



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